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isc N-Channel MOSFET Transistor

2SK430L

D(2)

S(3)

FEATURES

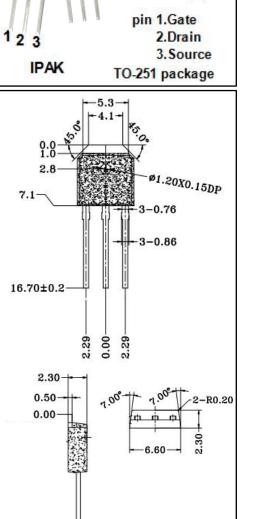
- Drain Current : I_D= 3.0A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage : V_{DSS}= 150V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 1.0 Ω (Max) @ V_{GS}= 15V

- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

 motor drive, DC-DC converter, power switch and solenoid drive.

| ABSOLUTE MAXIMUM RATINGS(Ta=25°C) | | | | | | | | |
|-----------------------------------|-------------------------------------|---------|------|--|--|--|--|--|
| SYMBOL | PARAMETER VALUE | | UNIT | | | | | |
| V _{DSS} | Drain-Source Voltage | 150 | V | | | | | |
| V _{GS} | Gate-Source Voltage-Continuous | ±20 | V | | | | | |
| ID | Drain Current-Continuous | 3.0 | A | | | | | |
| I _{DM} | Drain Current-Single Pluse | 6.0 | A | | | | | |
| P _D | Total Dissipation @Tc=25℃ | 20 | W | | | | | |
| TJ | Max. Operating Junction Temperature | -55~150 | °C | | | | | |
| T _{stg} | Storage Temperature | -55~150 | °C | | | | | |



THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT |
|---------------------|--------------------------------------|------|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 6.25 | °C/W |

isc website: <u>www.iscsemi.com</u>

0.50



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | ΜΙΝ | MAX | UNIT |
|----------------------|---------------------------------|--|-----|------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 10mA | 150 | | V |
| V _{GS} (th) | Gate Threshold Voltage | V _{DS} = 10V; I _D = 0.25mA | 1.0 | 4.0 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 15V; I _D = 2.0A | | 1.0 | Ω |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} = ±20V;V _{DS} = 0 | | ±1.0 | uA |
| IDSS | Zero Gate Voltage Drain Current | V _{DS} = 120V; V _{GS} = 0 | | 1.0 | mA |
| V _{SD} | Forward On-Voltage | I _S = 2.0A; V _{GS} = 0 | | 1.5 | V |

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